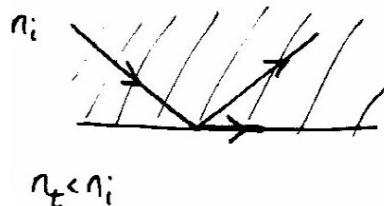


θ_c - critical angle for total int. reflection



$$n_i \sin \theta_c = n_t$$

$$\sin \theta_c = \frac{n_t}{n_i} = n_{ti}$$

for $\theta_i > \theta_c$ treatment is not quite right
(evanescent waves)

in general,

$$t_{\perp} - r_{\perp} = 1$$

Case (ii) $\vec{E} \parallel$ to plane of incidence

$$\Rightarrow \vec{B} \perp \text{ " " " }$$

$$ME \Rightarrow E_{oi} \cos \theta_i - E_{or} \cos \theta_r = E_{ot} \cos \theta_t$$

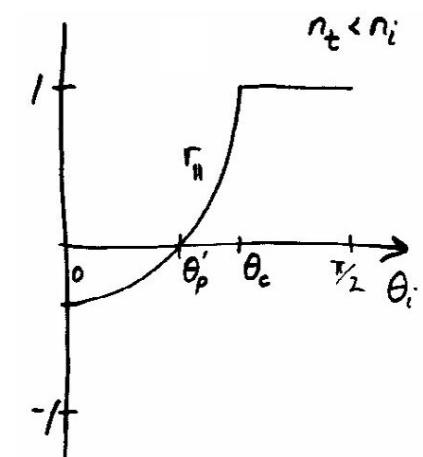
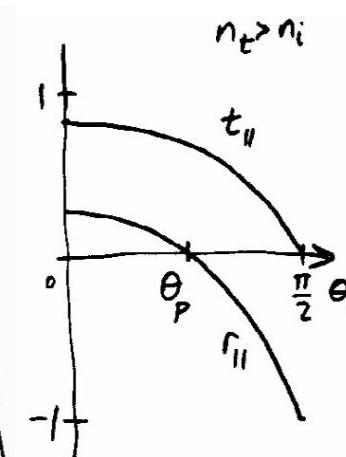
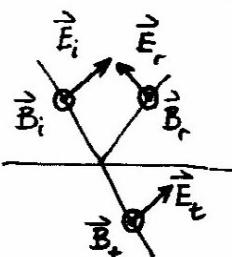
$$n_i E_{oi} + n_r E_{or} = n_t E_{ot}$$

$$\text{combine: } (\theta_r = \theta_i)$$

$$\left(\frac{E_{or}}{E_{oi}} \right)_{\parallel} = r_{\parallel} = \frac{n_t \cos \theta_i - n_i \cos \theta_t}{n_i \cos \theta_t + n_t \cos \theta_i}$$

$$\left(\frac{E_{ot}}{E_{oi}} \right)_{\parallel} = t_{\parallel} = \frac{2n_i \cos \theta_i}{n_i \cos \theta_t + n_t \cos \theta_i}$$

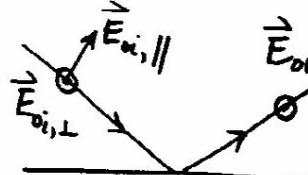
(r's and t's can be further simplified
(using Snell's law)).



note: $t_{\parallel} - r_{\parallel} \neq 1$, but $t_{\parallel} + r_{\parallel} = 1$
at normal incidence
again, for $\theta > \theta_c$ treatment not quite right.

look at θ_p "Brewster's angle"

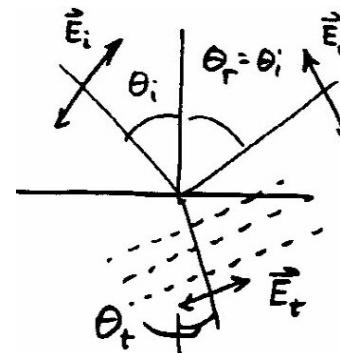
mixed
polarized
incident:



output only
 \perp polarization

why?

oscillators
don't emit
 \perp to their
oscillation
direction:



if $\theta_t + \theta_r = \pi/2$
then $E_r = 0$.

$$\theta_t = \pi/2 - \theta_i$$

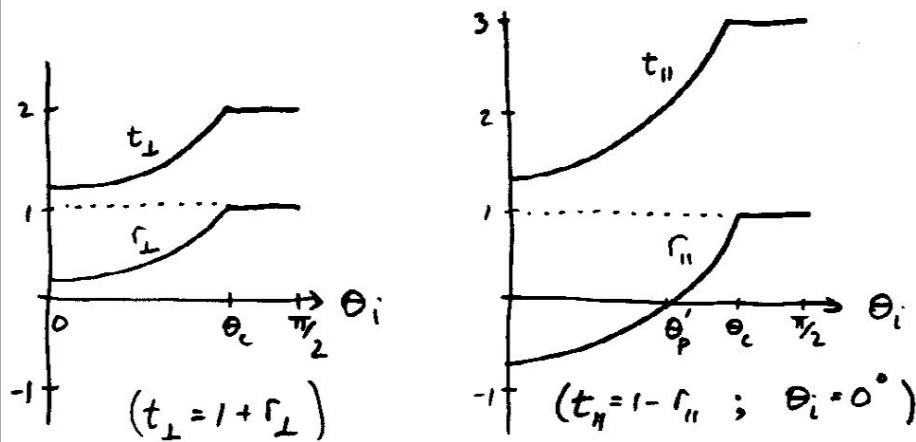
$$n_i \sin \theta_p = n_t \sin \theta_t$$

$$= n_t \cos \theta_p$$

$$\Rightarrow \boxed{\tan \theta_p = \frac{n_t}{n_i}}$$

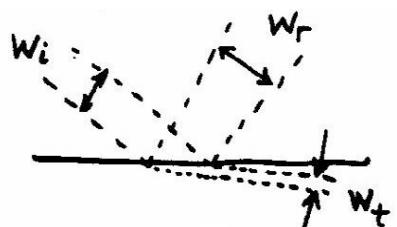
similarly
for θ_p'

return to examine t_{\perp}, t_{\parallel} for $n_t < n_i$:



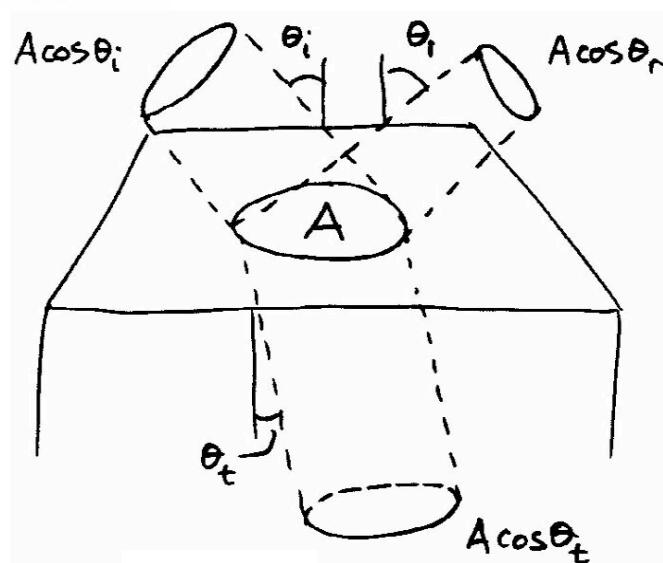
- find large t values! Does this violate conservation of energy?

No! cross-sectional area of beams also varies!



$w_t \rightarrow 0$ for $\theta_t \rightarrow \pi/2$
 \Rightarrow no energy in beam.

in detail:



I_i, I_r, I_t flux densities (intensities) (W/m^2)

incident power = $I_i A \cos \theta_i$

reflected " = $I_r A \cos \theta_r$

transmitted " = $I_t A \cos \theta_t$

then,

$$\text{reflectance } R = \frac{I_r A \cos \theta_r}{I_i A \cos \theta_i} = \frac{I_r}{I_i} \cos \theta_r$$

$$\text{transmittance } T = \frac{I_t A \cos \theta_t}{I_i A \cos \theta_i} = \frac{I_t \cos \theta_t}{I_i \cos \theta_i}$$

relate using $I_i A \cos \theta_i = I_r A \cos \theta_r + I_t A \cos \theta_t$

$$\text{and } I = \frac{\nu E}{2} E_0^2 = \frac{c n^2 E_0}{2n} E_0^2 \propto n E_0$$

$$\Rightarrow n_i E_{oi}^2 \cos \theta_i = n_i E_{or}^2 \cos \theta_i + n_t E_{ot}^2 \cos \theta_t$$

$$I = \left(\frac{E_{or}}{E_{oi}} \right)^2 + \frac{n_t \cos \theta_t}{n_i \cos \theta_i} \left(\frac{E_{ot}}{E_{oi}} \right)^2$$

or

$$I = R + T$$

also, can write

$$R = \left(\frac{E_{or}}{E_{oi}} \right)^2 = r^2$$

$$T = \frac{n_t \cos \theta_t}{n_i \cos \theta_i} \left(\frac{E_{ot}}{E_{oi}} \right)^2 = \frac{n_t \cos \theta_t}{n_i \cos \theta_i} t^2$$

$$\text{and } R_{\perp} = r_{\perp}^2, R_{\parallel} = r_{\parallel}^2$$

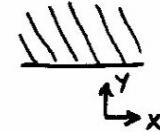
$$T_{\perp} = \frac{n_t \cos \theta_t}{n_i \cos \theta_i} t_{\perp}^2, T_{\parallel} = \frac{n_t \cos \theta_t}{n_i \cos \theta_i} t_{\parallel}^2$$

and find

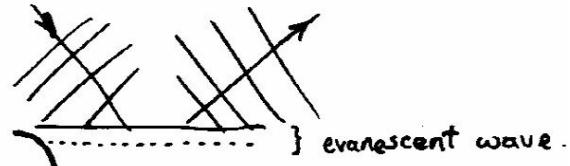
$$R_{\parallel} + T_{\parallel} = 1, R_{\perp} + T_{\perp} = 1$$

Evanescent Waves ($n_t < n_i, \theta_i > \theta_c$)

- impossible to satisfy boundary conditions with real values of k_y ;
need $k_y = i\beta$,



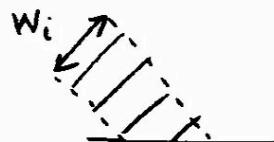
wave decays exponentially,



turns out,

$$\beta = \left(\frac{\sin \theta_i}{n_{ti}} - 1 \right)^{1/2} \rightarrow 0 \text{ as } \theta \rightarrow \theta_c$$

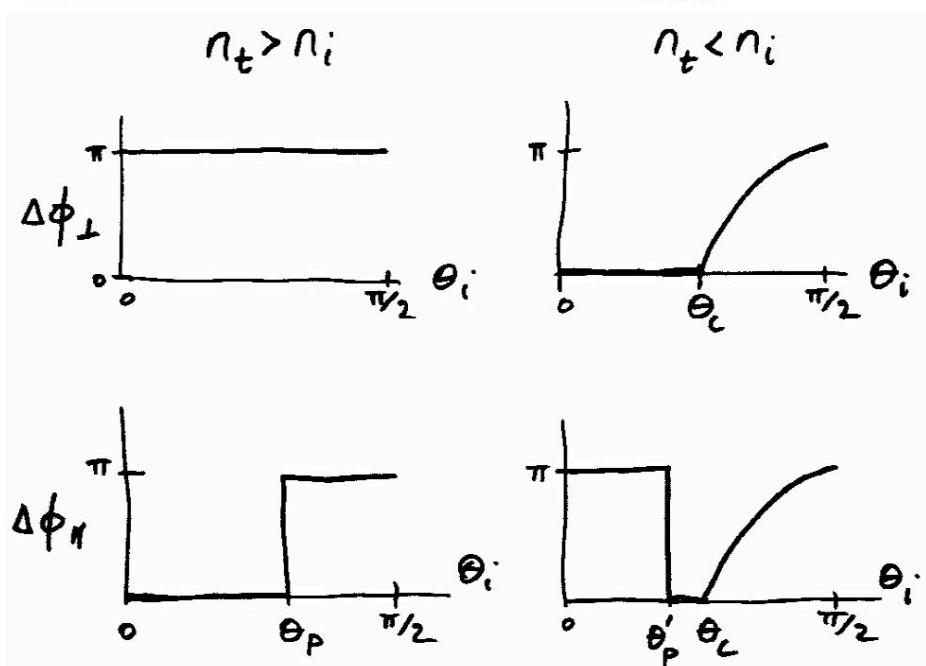
For incident wave of infinite extent ,



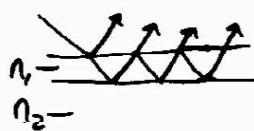
$w_i \rightarrow \infty$, then fraction of power in evanescent wave is zero.

(for finite w_i , then must consider diffraction at edges of incident wave).

Phase Shift of Reflected Wave:

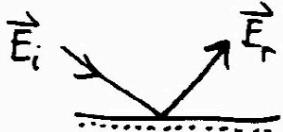


- very important for later applications of e.g. multiple reflections in thin films,



- application of Fresnel Eqns:

Ellipsometry



- measure polarization and amp. of reflected beam, vs. λ and/or vs. θ_i . Determine \tilde{n} for material and for thin films on material.